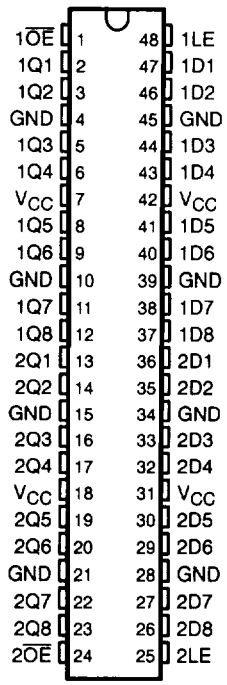
- **Members of the Texas Instruments *Widebus*™ Family**
- **Inputs Are TTL-Voltage Compatible**
- ***EPIC*™ (Enhanced-Performance Implanted CMOS) Process**
- **Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54AHCT16373 . . . WD PACKAGE
SN74AHCT16373 . . . DGG OR DL PACKAGE
(TOP VIEW)



description

The 'AHCT16373 are 16-bit transparent D-type latches with 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

$\overline{OE}$ does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN74AHCT16373 is available in TI's shrink small-outline (DL) and thin shrink small-outline (DGG) packages, which provide twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area.

The SN54AHCT16373 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT16373 is characterized for operation from –40°C to 85°C.

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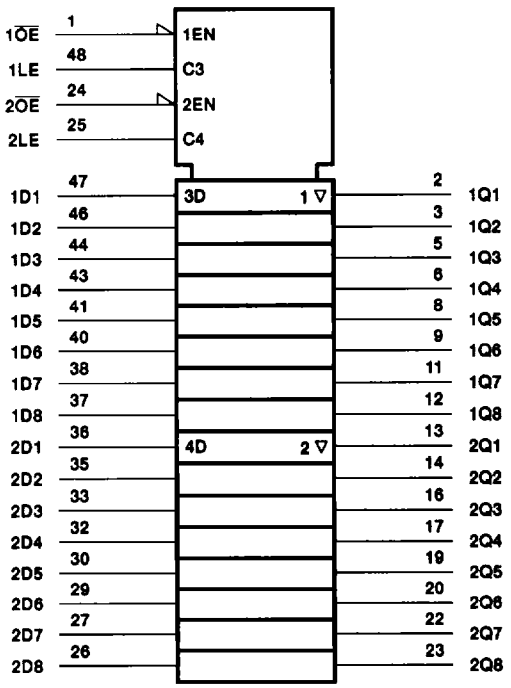
FUNCTION TABLE
(each latch)

INPUTS			OUTPUT
$\overline{OE}$	LE	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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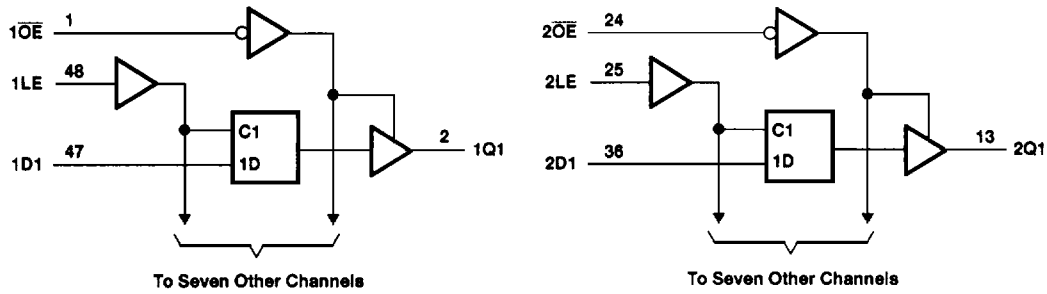
logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} ..... –0.5 V to 7 V
Input voltage range, V_I (see Note 1) ..... –0.5 V to 7 V
Output voltage range, V_O (see Note 1) ..... –0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) ..... –20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) ..... –20 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) ..... ±25 mA
Continuous current through each V_{CC} or GND ..... ±75 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DGG package ..... 0.85 W
DL package ..... 1.2 W
Storage temperature range, T_{stg} ..... –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

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recommended operating conditions (see Note 3)

		SN54AHCT16373		SN74AHCT16373		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	5.5	0	5.5	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–8		–8	mA
I_{OL}	Low-level output current		8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		20		20	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C			SN54AHCT16373		SN74AHCT16373		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	I_{OH} = –50 μA	4.5 V	3.15	3.65		3.15		3.15		V
	I_{OH} = –8 mA		2.5			2.4		2.4		
V_{OL}	I_{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
	I_{OL} = 8 mA				0.36		0.44		0.44	
I_{OZ}	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μA
I_I	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μA
I_{CC}	$V_I = V_{CC}$ or GND, I_O = 0	5.5 V			4		40		40	μA
ΔI_{CC}†	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5 V			1.35		1.5		1.5	mA
I_{off}	V_O = 5.5 V	0 V			0.5*				5	μA
C_i	$V_I = V_{CC}$ or GND	5 V		4						pF
C_o	$V_O = V_{CC}$ or GND	5 V		6						pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.
† This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

		T_A = 25°C		SN54AHCT16373		SN74AHCT16373		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration, $\overline{LE}$ high	6.5		6.5		6.5		ns
t_{su}	Setup time, data before $\overline{LE}$↓	1.5		1.5		1.5		ns
t_h	Hold time, data after $\overline{LE}$↓	3.5		3.5		3.5		ns

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T_A = 25°C			SN54AHCT16373		SN74AHCT16373		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}*	D	Q	C_L = 15 pF		5.1	8.5	1	9.5	1	9.5	ns
t_{PHL}*					5.1	8.5	1	9.5	1	9.5	
t_{PLH}*	LE	Q	C_L = 15 pF		7.7	12.3	1	13.5	1	13.5	ns
t_{PHL}*					7.7	12.3	1	13.5	1	13.5	
t_{PZH}*	$\overline{OE}$	Q	C_L = 15 pF		6.3	10.9	1	12.5	1	12.5	ns
t_{PZL}*					6.3	10.9	1	12.5	1	12.5	
t_{PHZ}*	$\overline{OE}$	Q	C_L = 15 pF		6	10.2	1	11	1	11	ns
t_{PLZ}*					6	10.2	1	11	1	11	
t_{PLH}	D	Q	C_L = 50 pF		5.9	9.5	1	10.5	1	10.5	ns
t_{PHL}					5.9	9.5	1	10.5	1	10.5	
t_{PLH}	LE	Q	C_L = 50 pF		8.5	13.3	1	14.5	1	14.5	ns
t_{PHL}					8.5	13.3	1	14.5	1	14.5	
t_{PZH}	$\overline{OE}$	Q	C_L = 50 pF		7.1	11.9	1	13.5	1	13.5	ns
t_{PZL}					7.1	11.9	1	13.5	1	13.5	
t_{PHZ}	$\overline{OE}$	Q	C_L = 50 pF		6.8	11.2	1	12	1	12	ns
t_{PLZ}					6.8	11.2	1	12	1	12	

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

output-skew characteristics, C_L = 50 pF (see Note 4)

PARAMETER		V_{CC}	SN74AHCT16373				UNIT
			T_A = 25°C		MIN	MAX	
			MIN	MAX			
$t_{sk(o)}$	Output skew	5 V ± 0.5 V		1		1	ns

NOTE 4: Characteristics are determined during product characterization and ensured by design.

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 5)

PARAMETER		SN74AHCT16373			UNIT
		MIN	TYP	MAX	
$V_{OL(P)}$	Quiet output, maximum dynamic V_{OL}		0.8	1.2	V
$V_{OL(V)}$	Quiet output, minimum dynamic V_{OL}		–0.8	–1.2	V
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}	4.1			V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 5: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	17	pF

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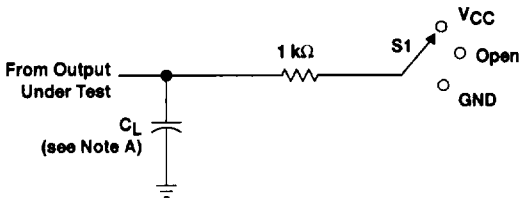
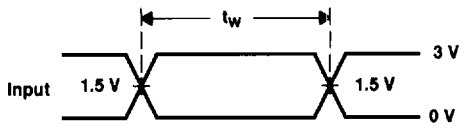
PARAMETER MEASUREMENT INFORMATION

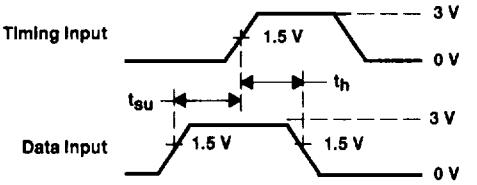


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND

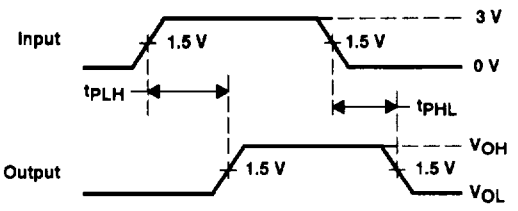
LOAD CIRCUIT



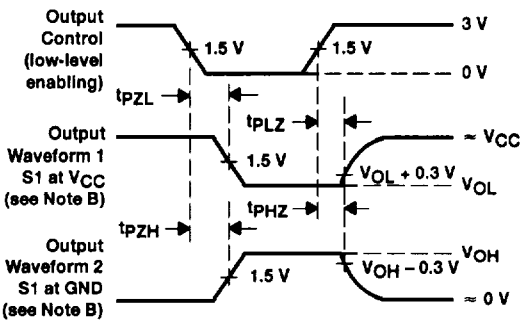
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r = 3 ns, t_f = 3 ns.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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